재료상변태

Phase Transformation of Materials

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Contents for previous class

각 온도의 G-X 관계 도식 😝 T-X 관계 도식으로 plot

Binary Phase Diagrams

 $G = X_{A}G_{A} + X_{B}G_{B} + \Omega X_{A}X_{B} + RT(X_{A}\ln X_{A} + X_{B}\ln X_{B})$

- 1) Simple Phase Diagrams
- 2) Systems with Miscibility Gap
- 3) Simple Eutectic Systems
- 4) Ordered Alloys

- $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} = 0$ $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} > 0$ $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} >> 0$ $\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} < 0$
- 5) Phase dia. containing stable intermediate phases

$$\Delta H_{mix}^{L} = 0 \quad \Delta H_{mix}^{S} << 0$$

Contents for today's class

- Effect of Temperature on Solid Solubility
- Equilibrium Vacancy Concentration
- The Influence of Interfaces on Equilibrium
- Ternary Equilibrium: Ternary Phase Diagram

Effect of T on solid solubility



$$\mu_{B}^{\alpha} = {}^{o}G_{B}^{\alpha} + \Omega(1 - X_{B})^{2} + RT \ln X_{B}$$

$$\Delta G_{B}^{\beta \to \alpha} = {}^{0}G_{B}^{\alpha} - {}^{o}G_{B}^{\beta} = {}^{o}G_{B}^{\alpha} - \mu_{B}^{\beta} = {}^{o}G_{B}^{\alpha} - \mu_{B}^{\alpha}$$

$${}^{o}G_{B}^{\alpha} - \mu_{B}^{\alpha} = -\Omega(1 - X_{B})^{2} - RT \ln X_{B}$$

$$\Delta G_{B}^{\beta \to \alpha} = -\Omega(1 - X_{B})^{2} - RT \ln X_{B}$$

$$RT \ln X_{B} = -\Delta G_{B}^{\beta \to \alpha} - \Omega(1 - X_{B})^{2}$$

$$(here, X_{B}^{e} <<1)$$

$$RT \ln X_{B}^{e} = -\Delta G_{B}^{\beta \to \alpha} - \Omega$$

$$> X_{B}^{e} = \exp(-\frac{\Delta G_{B}^{\beta \to \alpha} + \Omega}{RT})$$

$$\Delta G_{B}^{\beta \to \alpha} = \Delta H_{B}^{\beta \to \alpha} - T\Delta S_{B}^{\beta \to \alpha} \circ] \boxminus \Xi$$

$$X_{B}^{e} = \exp(\frac{\Delta S_{B}^{\beta \to \alpha}}{R}) \exp(-\frac{\Delta H_{B}^{\beta \to \alpha} + \Omega}{RT})$$

$$X_{B}^{e} = A \exp\left\{-\frac{Q}{RT}\right\}$$

 $T \uparrow \implies X_{B}^{e} \uparrow$

Q: heat absorbed (enthalpy) when 1 mole of β dissolves in A rich α as a dilute solution.

Equilibrium Vacancy Concentration $\Delta G = \Delta H - T \Delta S$

• Vacancies increase the internal energy of crystalline metal due to broken bonds formation.

 $\Delta H \cong \Delta H_V X_V$

- Vacancies increase entropy because they change the thermal vibration frequency and also the configurational entropy.
- Total entropy change is thus

$$\Delta S = \Delta S_{\vee} X_{\vee} - R\{X_{\vee} \ln X_{\vee} + (1 - X_{\vee}) \ln(1 - X_{\vee})\}$$

The molar free energy of the crystal containing X_v mol of vacancies

$$\mathbf{G} = \mathbf{G}_{\mathsf{A}} + \Delta \mathbf{G} = \mathbf{G}_{\mathsf{A}} + \Delta \mathbf{H}_{\mathsf{V}} \mathbf{X}_{\mathsf{V}} - \mathsf{T} \Delta \mathbf{S}_{\mathsf{V}} \mathbf{X}_{\mathsf{V}} + \mathsf{RT} \{ \mathbf{X}_{\mathsf{V}} \ln \mathbf{X}_{\mathsf{V}} + (1 - \mathbf{X}_{\mathsf{V}}) \ln(1 - \mathbf{X}_{\mathsf{V}}) \}$$

With this information, estimate the equilibrium vacancy concentration.



$$\left(rac{\mathrm{dG}}{\mathrm{dX}_{\mathrm{V}}}
ight)_{\mathrm{X}_{\mathrm{V}}\,=\mathrm{X}_{\mathrm{V}}^{\mathrm{e}}}\,=0$$

$$\Delta H_{v} - T\Delta S_{v} + RT \ln X_{v}^{e} = 0$$

$$X_{V}^{e} = exp \frac{\Delta S_{V}}{R} \cdot exp \frac{-\Delta H_{V}}{RT}$$
putting $\Delta G_{V} = \Delta H_{V} - T\Delta S_{V}$

$$X_{V}^{e} = exp \frac{-\Delta G_{V}}{RT}$$

RT

 In practice △H_V is of the order of 1 eV per atom and X_V^e reaches a value of about 10⁴~10⁻³ at the melting point of the solid



Fig. 1.37 Equilibrium vacancy concentration.

Interface (α/β)= γ

G





Fig. 1.38 The effect of interfacial energy on the solubility of small particles.





Fig. 1.39 Transfer of dn mol of β from large to a small particle.

$$\Delta G = \frac{2\gamma V_m}{r} \qquad \Delta G \cong \frac{L\Delta T}{T_m}$$

$$r^* = \frac{2\gamma}{\Delta G_V} = \frac{2\gamma T_m}{L\Delta T}$$
$$\Delta T \uparrow, r^* \downarrow$$

 β formation in α

 β Nucleation & growth in α

Interface (α/β) : size barrier composition barrier

Undercooling이 클수록 r*가 작다

- → Nucleation ↑β 상의 수
- \rightarrow size barrier (r*)



The Gibbs-Duhem Equation

Be able to calculate the change in chemical potential ($d\mu$) that result from a change in alloy composition (dX).

For a regular solution,

$$G = X_A G_A + X_B G_B + \Omega X_A X_B + RT(X_A \ln X_A + X_B \ln X_B)$$
$$\frac{d^2 G}{dX^2} = \frac{RT}{X_A X_B} - 2\Omega$$
For a ideal solution, $\Omega = 0$, $\frac{d^2 G}{dX^2} = \frac{RT}{X_A X_B}$

$$\mu_{\rm B} = \mathbf{G}_{\rm B} + \mathbf{RT} \ln \mathbf{a}_{\rm B} = \mathbf{G}_{\rm B} + \mathbf{RT} \ln \gamma_{\rm B} \mathbf{X}_{\rm B}$$
$$\frac{d\,\mu_{\rm B}}{dX_{\rm B}} = \frac{RT}{X_{\rm B}} \left\{ 1 + \frac{X_{\rm B}}{\gamma_{\rm B}} \frac{d\,\gamma_{\rm B}}{dX_{\rm B}} \right\} = \frac{RT}{X_{\rm B}} \left\{ 1 + \frac{d\,\ln\gamma_{\rm B}}{d\,\ln X_{\rm B}} \right\}$$

a similar relationship can be derived for $d\mu_A/dX_B$

$$-X_A d\mu_A = X_B d\mu_B = RT \left\{ 1 + \frac{d\ln\gamma_A}{d\ln X_A} \right\} dX_B = RT \left\{ 1 + \frac{d\ln\gamma_B}{d\ln X_B} \right\} dX_B$$

$$-X_A d\mu_A = X_B d\mu_B = X_A X_B \frac{d^2 G}{dX^2} dX_B$$

$$X_A X_B \frac{d^2 G}{dX^2} = RT \left\{ 1 + \frac{d \ln \gamma_A}{d \ln X_A} \right\} = RT \left\{ 1 + \frac{d \ln \gamma_B}{d \ln X_B} \right\}$$

Driving force: precipitation

- * Consider the chemical potential of component *B* in phase *alpha* compared to *B* in *beta*. This difference, labeled as ΔG_n on the right of the lower diagram is the driving force (expressed as energy per mole, in this case).
- * To convert to *energy/volume*, divide by the molar volume for *beta*: $\Delta G_V = \Delta G_n / V_m$.

Driving force for the reaction : ΔG_0

Driving force for nucleation : ΔG_n

Because the first nuclei of beta to appear do not ignificantly change the composition of the parent material



Fig. 5.3 Free energy changes during precipitation. The driving force for the first precipitates to nucleate is $\Delta G_n = \Delta G_v V_m$. ΔG_0 is the total decrease in free energy when precipitation is complete and equilibrium has been reached.



What are ternary phase diagram?

Diagrams that represent the equilibrium between the various phases that are formed between three components, as a function of temperature.

Normally, pressure is not a viable variable in ternary phase diagram construction, and is therefore held constant at 1 atm.

장영진, 이양은 학생 제공 자료 참고 www.sjsu.edu/faculty/selvaduray/page/phase/ternary_p_d.pdf **Gibbs Phase Rule for 3-component Systems**

F = C + 2 - P For isobaric systems: F = C + 1 - P

For C = 3, the maximum number of phases will co-exist when F = 0

$$P = 4$$
 when $C = 3$ and $F = 0$

Components are "independent components"

Gibbs Triangle

An Equilateral triangle on which the pure

components are represented by each corner.



Concentration can be expressed as either "wt. %" or "at.% = molar %".

 $X_{A}+X_{B}+X_{C}=1$

Used to determine the overall composition

Overall Composition



Overall Composition



Isomorphous System: A system (ternary in this case) that has only one solid phase. All components are totally soluble in the other components. The ternary system is therefore made up of three binaries that exhibit total solid solubility

<u>The Liquidus Surface</u>: A plot of the temperatures above which a homogeneous liquid forms for any given overall composition

The Solidus Surface: A plot of the temperatures below which a (homogeneous) solid phase forms for any given overall composition











Isothermal section \rightarrow F = C - P



Isothermal section



Ternary Isomorphous System Isothermal section \rightarrow F = C - P



Locate overall composition using Gibbs triangle



<u>Tie line</u>: A straight line joining any two ternary compositions

Amount of each phase present is determined by using the Inverse Lever Rule

5. Fraction of solid = YX/YZ

6. Fraction of liquid = ZX/YZ

Ternary Eutectic System – No Solid Solubility

The Ternary Eutectic Reaction:

 $\mathsf{L} = \alpha + \beta + \gamma$

A liquid phase solidifies into three separate solid phases

Made up of three binary eutectic systems, all of which exhibit no solid solubility

Ternary Eutectic System



















T= ternary eutectic temp.





- TA: Melting Point Of Material A
- T_B: Melting Point Of Material B
- T_C: Melting Point Of Material C
- TEI: Eutectic Temperature Of A-B
- T_{E2}: Eutectic Temperature Of B-C
- TE3: Eutectic Temperature Of C-A





Main outline of Ternary Phase Diagram with Ternary Eutectic (Te) and Solid Single Phase Regions Shown







T= ternary eutectic temp.

http://www.youtube.com/watch?v=yzhVomAdetM

Ternary Eutectic System

Solidification Sequence

Ternary Eutectic System

Solidification Sequence

2 상영역에서 수직 단면이 tie line과 불일 치하므로 다른 온도에서 평형상만 나타내 고 조성은 표시할 수 없음.

